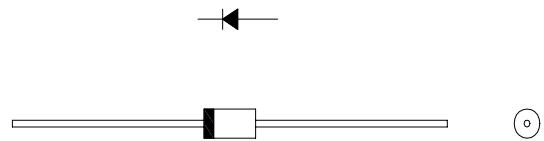


DIODE Type : 20E1

OUTLINE DRAWING

FEATURES

- * Miniature Size
- * Low Forward Voltage drop
- * Low Reverse Leakage Current
- * High Surge Capability
- * 52mm Inside Tape Spacing Package Available



Maximum Ratings

Approx Net Weight:0.38g

Rating	Symbol	20E1			Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	100			V	
Non-repetitive Peak Reverse Voltage	V _{RSM}	250			V	
Average Rectified Output Current	I _O	1.3	T _a =33°C *1	50Hz Half Sine Wave Resistive Load	A	
		1.7	T _a =43°C *2			
RMS Forward Current	I _{F(RMS)}	2.67			A	
Surge Forward Current	I _{FSM}	80	50Hz Half Sine Wave, 1cycle, Non-repetitive			
Operating JunctionTemperature Range	T _{jw}	- 40 to + 150			°C	
Storage Temperature Range	T _{stg}	- 40 to + 150			°C	

Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions		Min.	Typ.	Max.	Unit
Peak Reverse Current	I _{RM}	T _j = 25°C, V _{RM} = V _{RRM}		-	-	10	µA
Peak Forward Voltage	V _{FM}	T _j = 25°C, I _{FM} = 1.7A		-	-	0.92	V
Thermal Resistance	R _{th(j-a)}	Junction to Ambient		*1	-	105	°C/W
				*2		70	

*1 : Without Fin or P.C. Board

*2 : P.C. Board Mounted (L=8mm, Print Land=15 x 15mm, Both Sides)

20E1 OUTLINE DRAWING (Dimensions in mm)

